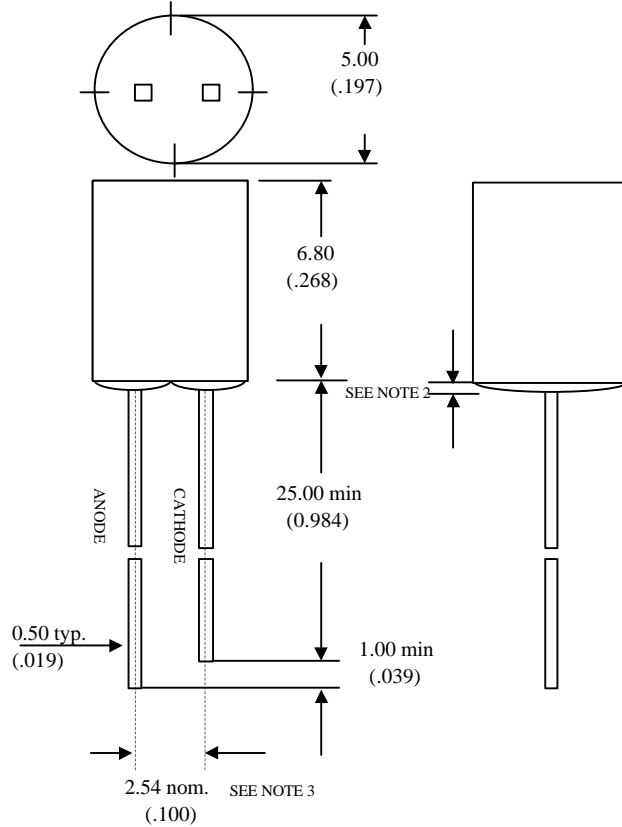


Description

The MVL-584BG, a blue source color device, is made with InGaN (on SiC substrate) LED die. The package is T-1 3/4 (φ5mm) water clear plastic type.

Package Dimensions

Unit : mm (inches)



- Notes :
1. Tolerance is ± 0.25 mm (.010") unless otherwise noted.
 2. Protruded resin under flange is 1.5 mm (.059") max.
 3. Lead spacing is measured where the leads emerge from the package.

Applications

- Full color displays & moving message signs
- Solid state incandescent replacement bulbs
- High ambient panel indicators
- Color printers & scanners
- Medical & Analytical instruments

Features

- High performance - 2.5mW (490nm)
- Superior SiC substrate technology
- Excellent chip to chip consistency
- High reliability

Absolute Maximum Ratings

@ T_A=25°C

Parameter	Symbol	Maximum Rating	Unit
Peak Forward Current(1/10 Duty Cycle@1KHz)	I _{pf}	100	mA
Continuous Forward Current	I _{af}	30	mA
Reverse Voltage	V _R	5	V
Operating Temperature Range	T _{opr}	-20°C to +80°C	
Storage Temperature Range	T _{stg}	-30°C to +100°C	
Electrostatic Discharge Threshold(HBM)	E _{ot}	1000	V

Optical-Electrical Characteristics

@ T_A=25°C

Parameter	Test Conditions	Symbol	Min .	Typ .	Max .	Unit .
Luminous Intensity	I _F =20mA	I _V	60	120	-	mcd
Forward Voltage	I _F =20mA	V _F	-	3.5	4.0	V
Reverse Current	V _R =5V	I _R	-	-	10	μA
Dominant Wavelength	I _F =20mA	λ _d	-	490	-	nm
Viewing Angle	I _F =20mA	2θ _{1/2}	-	75	-	deg.

Typical Optical-Electrical Characteristic Curves

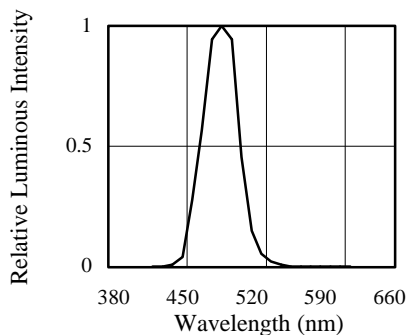


FIG.1 RELATIVE INTENSITY LUMINOUS VS. WAVELENGTH

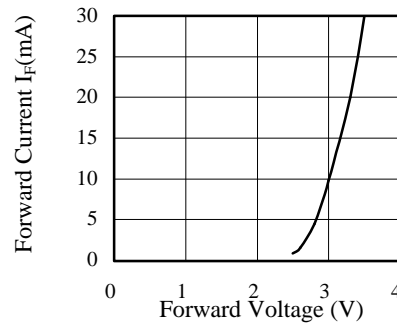


FIG.2 FORWARD CURRENT VS. FORWARD VOLTAGE

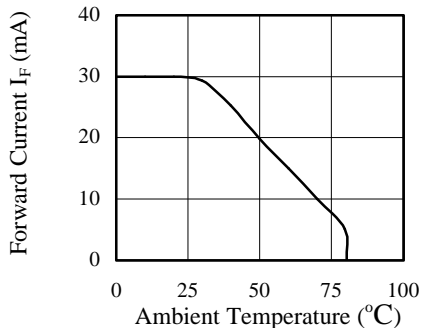


FIG.3 FORWARD CURRENT VS. AMBIENT TEMPERATURE

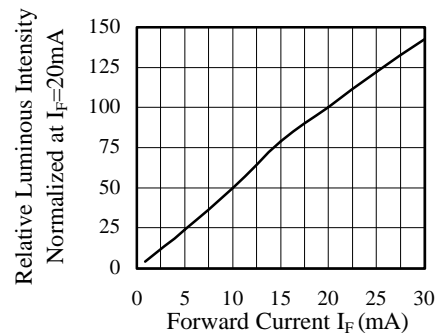


FIG.4 RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

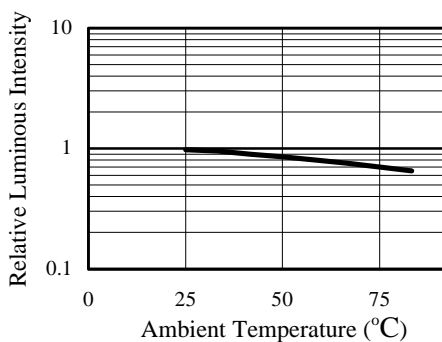


FIG.5 LUMINOUS INTENSITY VS. AMBIENT TEMPERATURE

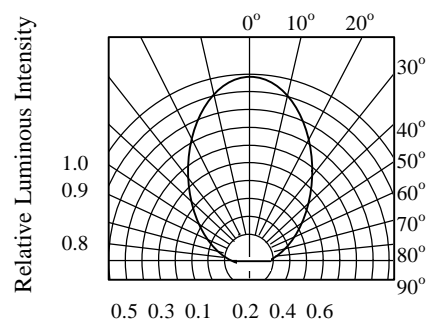


FIG.6 RADIATION DIAGRAM